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Vishay High Power Products

Phase Control SCR TO-220AB FULL-PAK, 25 A



PRODUCT SUMMARY			
V _T at 16 A	< 1.25 V		
I _{TSM}	300 A		
V _{RRM}	800/1200 V		

DESCRIPTION/FEATURES

The 25TTS...FP High Voltage Series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature.

Typical applications are in input rectification (soft start) and these products are designed to be used with Vishay HPP input diodes, switches and output rectifiers which are available in identical package outlines.

The fully isolated package ($V_{INS} = 2500 V_{RMS}$) is UL E78996 approved. Plastic material $94V_{Ro}$.

This product has been designed and qualified for industrial level.

OUTPUT CURRENT IN TYPICAL APPLICATIONS					
APPLICATIONS	SINGLE-PHASE BRIDGE	THREE-PHASE BRIDGE	UNITS		
Capacitive input filter $T_A = 55 \text{ °C}$, $T_J = 125 \text{ °C}$, common heatsink of 1 °C/W	18	22	A		

MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	TEST CONDITIONS	VALUES	UNITS	
I _{T(AV)}	Sinusoidal waveform	16	٨	
I _{RMS}		25	A	
V _{RRM} /V _{DRM}		800/1200	V	
I _{TSM}		300	А	
V _T	16 A, T _J = 25 °C	1.25	V	
dV/dt		500	V/µs	
dl/dt		150	A/µs	
TJ		- 40 to 125	٥°	

VOLTAGE RATINGS					
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{DRM} , MAXIMUM PEAK DIRECT VOLTAGE V	I _{RRM} /I _{DRM} AT 125 °C mA		
25TTS08FP	800	800	10		
25TTS12FP	1200	1200			

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ABSOLUTE MAXIMUM RATINGS					
DADAMETED	SYMBOL	TEST CONDITIONS		VALUES	
				MAX.	UNITS
Maximum average on-state current	I _{T(AV)}	$T_C = 85 \ ^{\circ}C$, 180° conduction half sine wave	1	6	
Maximum RMS on-state current	I _{RMS}		2	5	_
Maximum peak, one-cycle,		10 ms sine pulse, rated V_{RRM} applied	30	300	A
non-repetitive surge current	ITSM	10 ms sine pulse, no voltage reapplied	35	50	1
Maximum l ² t for fueing	12+	10 ms sine pulse, rated V_{RRM} applied	450		A20
Maximum - tion rusing	1-1	10 ms sine pulse, no voltage reapplied		630	
Maximum I ² √t for fusing	l²√t	t = 0.1 to 10 ms, no voltage reapplied	63	00	A²√s
Maximum on-state voltage drop	V _{TM}	16 A, T _J = 25 °C	1.2	25	V
On-state slope resistance	r _t	T _J = 125 °C		.0	mΩ
Threshold voltage	V _{T(TO)}			0	V
Maximum rayaraa and diract laakaga aurrant	1 /1	$T_J = 25 \text{ °C}$	0.5		
Maximum reverse and direct leakage current	IRM/IDM	$T_J = 125 \text{ °C}$	1	0	m 4
Holding current	Ι _Η	Anode supply = 6 V, resistive load, initial $I_T = 1 A$ - 10		100	
Maximum latching current	١L	Anode supply = 6 V, resistive load 200			
Maximum rate of rise of off-state voltage	dV/dt		50	00	V/µs
Maximum rate of rise of turned-on current	dl/dt		15	50	A/μs

TRIGGERING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum peak gate power	P _{GM}		8.0	\A/
Maximum average gate power	P _{G(AV)}		2.0	vv
Maximum peak positive gate current	+ I _{GM}		1.5	А
Maximum peak negative gate voltage	- V _{GM}		10	V
Maximum required DC gate current to trigger	I _{GT}	Anode supply = 6 V, resistive load, T_J = - 10 °C	60	mA
		Anode supply = 6 V, resistive load, $T_J = 25 \ ^{\circ}C$	45	
		Anode supply = 6 V, resistive load, $T_J = 125 \degree C$ 2	20	
		Anode supply = 6 V, resistive load, T_J = - 10 °C	2.5	
Maximum required DC gate voltage to trigger	V_{GT}	Anode supply = 6 V, resistive load, $T_J = 25 \degree C$ 2.0	2.0	
	Anode supply = 6 V, resistive load, T_J = 125 °C	1.0	v	
Maximum DC gate voltage not to trigger	V_{GD}	T _J = 125 °C, V _{DRM} = Rated value		
Maximum DC gate current not to trigger	I _{GD}			mA

SWITCHING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Typical turn-on time	t _{gt}	T _J = 25 °C	0.9	
Typical reverse recovery time	t _{rr}	T - 125 °C	4	μs
Typical turn-off time	t _q	1J = 125 C	110	

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THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T _J , T _{Stg}		- 40 to 125	°C
Maximum thermal resistance, junction to case		R _{thJC}	DC operation	1.5	
Maximum thermal resistance, junction to ambient		R _{thJA}		62	°C/W
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	1.5	
Approximato woight				2	g
Approximate weight				0.07	oz.
Mounting torque	minimum			6 (5)	kgf ⋅ cm
maximum	maximum			12 (10)	(lbf ⋅ in)
Martine device				25TTS08FP	
			Case sigle 10-220AD FULL-FAR (94/VU)		2FP

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Fig. 5 - Maximum Non-Repetitive Surge Current



Fig. 6 - Maximum Non-Repetitive Surge Current



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Fig. 7 - On-State Voltage Drop Characteristics











ORDERING INFORMATION TABLE



LINKS TO RELATED DOCUMENTS			
Dimensions	http://www.vishay.com/doc?95072		
Part marking information	http://www.vishay.com/doc?95069		



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